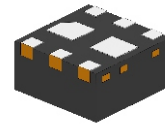


CMSA06CP02A06K-HF

P-Channel
RoHS Device
Halogen Free



Features

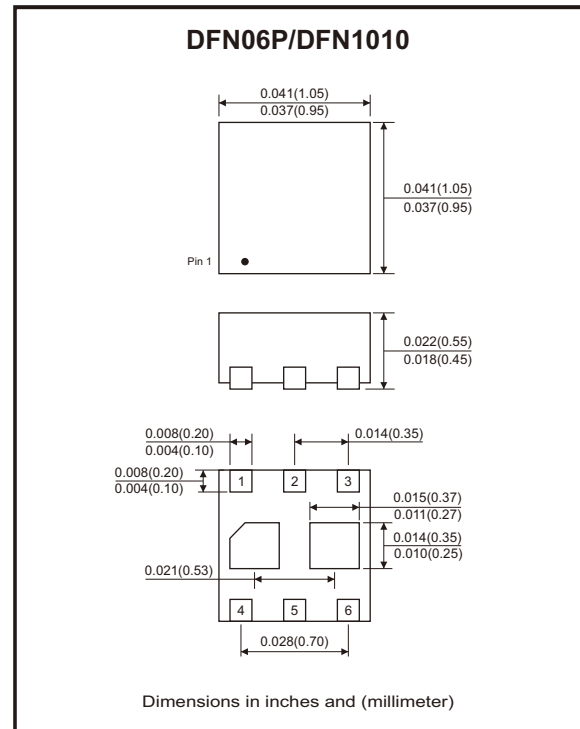
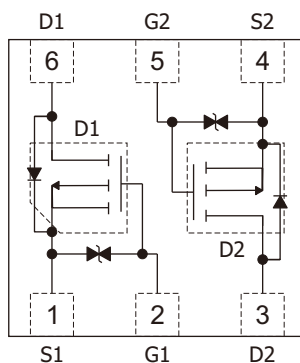
- Surface mount package.
- Reliable and rugged.
- ESD protection.
- Human body model (HBM) 2kV
- Charge device model (CDM) 1kV

Mechanical data

- Case: DFN06P/DFN1010 package, molded plastic.
- Mounting position: Any.

Circuit Diagram

- G : Gate
- S : Source
- D : Drain



Maximum Ratings (at $T_A=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-source voltage	V_{DS}	-20	V
Gate-source voltage	V_{GS}	± 8	V
Continuous drain current	I_D	-900	mA
Power dissipation	P_D	600	mW
Thermal resistance, junction to ambient @ $T_A=25^{\circ}\text{C}$	$R_{\theta JA}$	164	$^{\circ}\text{C/W}$
Operating junction and storage temperature range	T_J, T_{STG}	-55 to +150	$^{\circ}\text{C}$

Electrical Characteristics (at $T_A=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Static Electrical Characteristics						
Drain-source breakdown voltage	BV_{DSS}	$V_{GS} = 0V, I_D = -250\mu A$	-20			V
Zero gate voltage drain current	I_{DSS}	$V_{DS} = -16V, V_{GS} = 0V$			-0.6	μA
Gate leakage current	I_{GSS}	$V_{GS} = \pm 8V, V_{DS} = 0V$			± 10	μA
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250\mu A$	-0.3		-1.0	V
Drain source on-state resistance	$R_{DS(on)}$	$V_{GS} = -4.5V, I_D = -500mA$		450	560	m Ω
		$V_{GS} = -2.5V, I_D = -500mA$		570	780	
		$V_{GS} = -1.8V, I_D = -100mA$		690	1100	
		$V_{GS} = -1.5V, I_D = -50mA$		820	1400	
		$V_{GS} = -1.2V, I_D = -10mA$		1160	2200	
Drain forward voltage	V_{SD}	$V_{GS} = 0V, I_S = -300mA$	-0.4		-1.2	V
Dynamic Characteristics						
Input capacitance	C_{iss}	$V_{DS} = -10V, V_{GS} = 0V, f = 1MHz$		40		pF
Output capacitance	C_{oss}			12		
Reverse transfer capacitance	C_{rss}			6		

Typical Rating and Characteristic Curves (CMSA06CP02A06K-HF)

Fig.1 - On-Region Characteristics

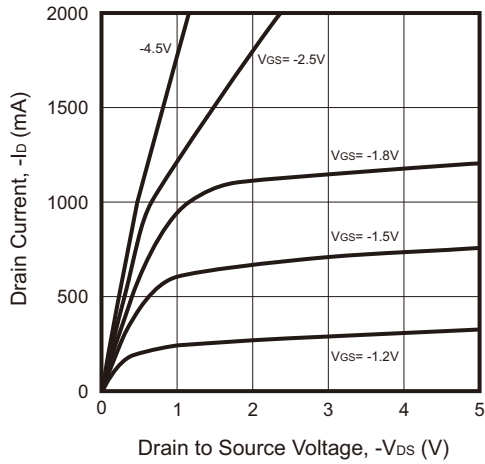


Fig.2 - Transfer Characteristics

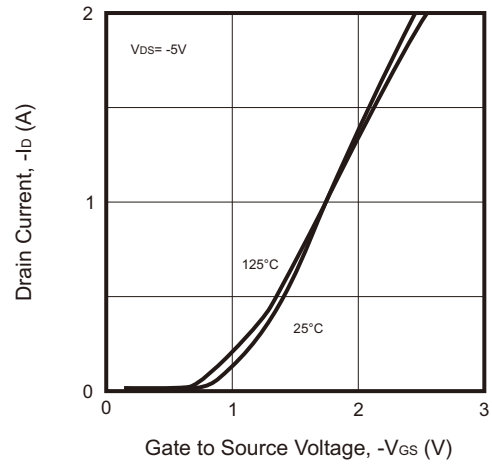


Fig.3 - On-Resistance vs. Drain Current Gate Voltage

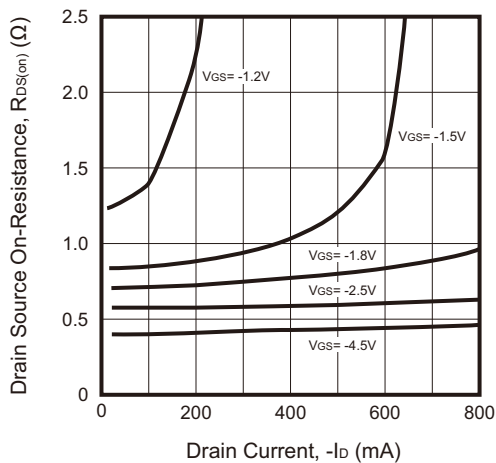


Fig.4 - On-Resistance Variation with Temperature

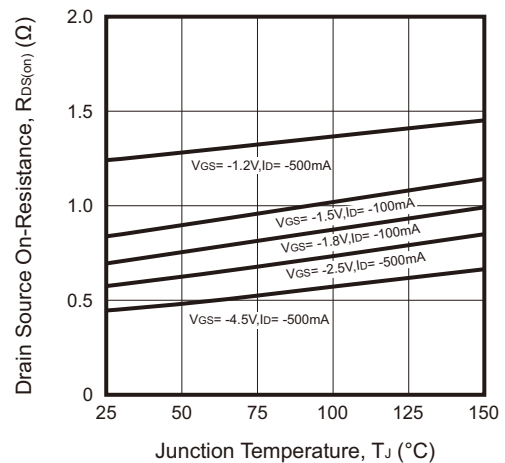


Fig.5 - On-Resistance vs. Gate Source Voltage

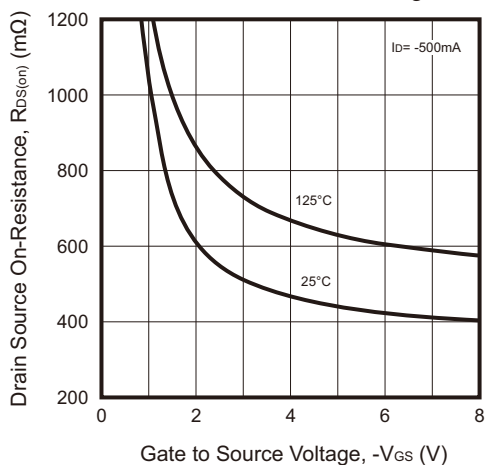
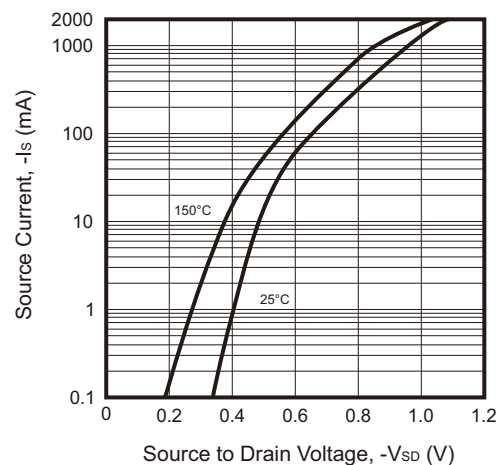


Fig.6 - Diode Forward Voltage vs. Current



Typical Rating and Characteristic Curves (CMSA06CP02A06K-HF)

Fig.7 - Gate Threshold Variation
vs. Ambient Temperature

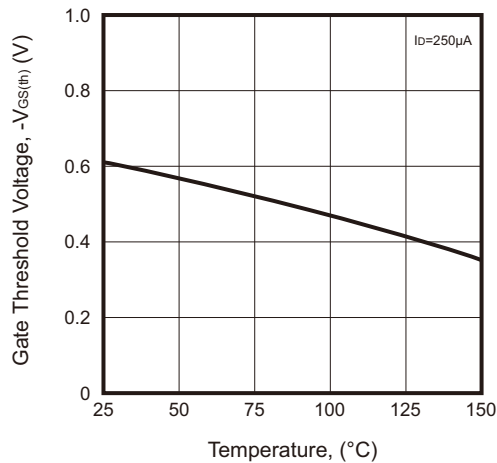


Fig.8 - Breakdown Voltage vs. Temperature

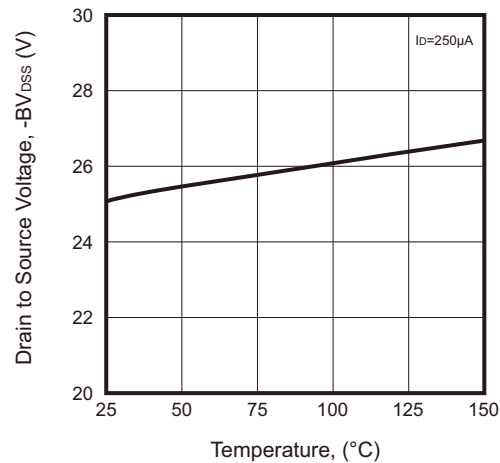
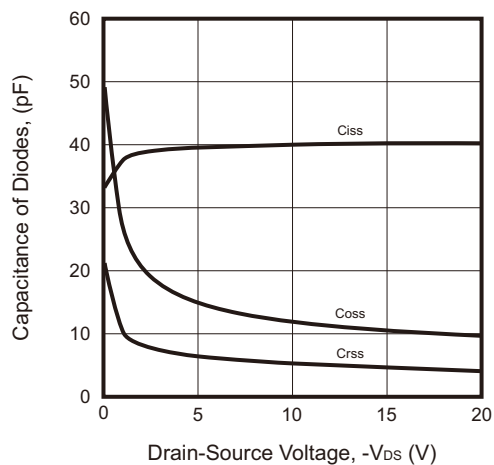
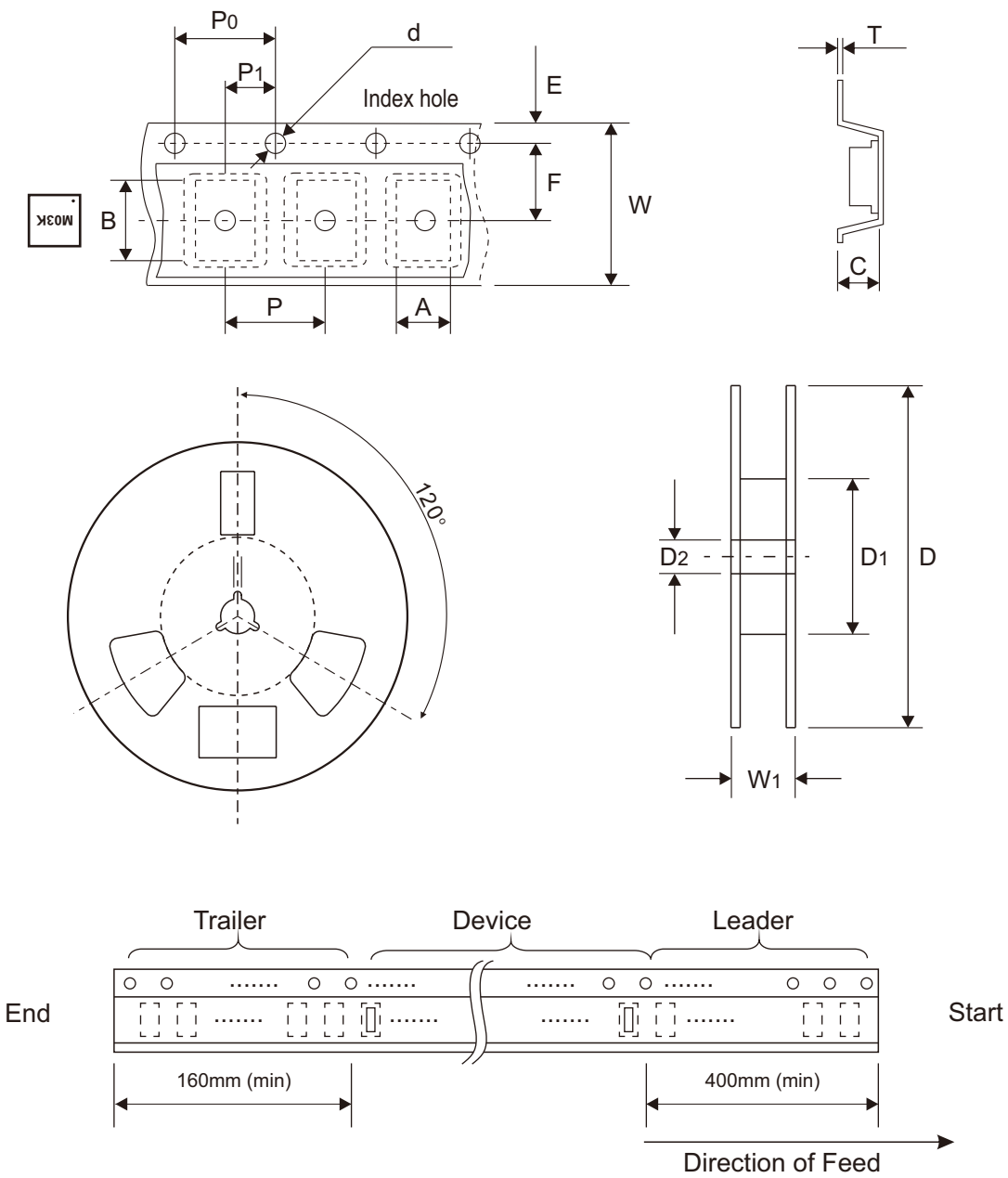


Fig.9 - Capacitance of Diodes



Reel Taping Specification



DFN06P/ DFN1010	SYMBOL	A	B	C	d	D	D1	D2
	(mm)	1.13 ± 0.05	1.13 ± 0.05	0.65 ± 0.05	1.50 + 0.10 - 0.00	178.00 ± 1.00	60.00 ± 0.50	13.50 ± 0.20
	(inch)	0.044 ± 0.002	0.044 ± 0.002	0.026 ± 0.002	0.059 + 0.004 - 0.000	7.008 ± 0.039	2.362 ± 0.020	0.531 ± 0.008

DFN06P/ DFN1010	SYMBOL	E	F	P	P0	P1	T	W	W1
	(mm)	1.75 ± 0.10	3.50 ± 0.05	4.00 ± 0.10	4.00 ± 0.10	2.00 ± 0.05	0.20 ± 0.05	8.00 + 0.30 - 0.10	12.00 + 0.50 - 0.00
	(inch)	0.069 ± 0.004	0.138 ± 0.002	0.157 ± 0.004	0.157 ± 0.004	0.079 ± 0.002	0.008 ± 0.002	0.315 + 0.012 - 0.001	0.472 + 0.020 - 0.000

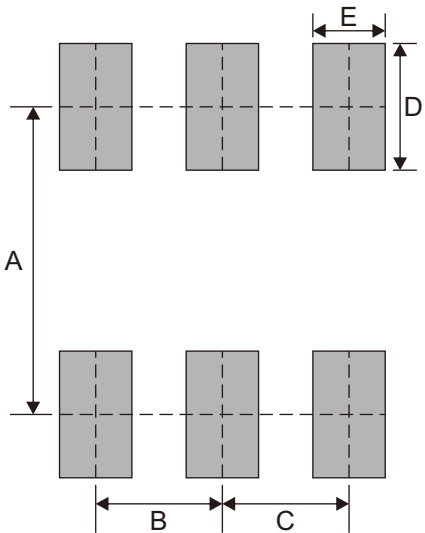
Marking Code

Part Number	Marking Code
CMSA06CP02A06K-HF	.M06K



Suggested P.C.B. PAD Layout

SIZE	DFN06P /DFN1010	
	(mm)	(inch)
A	0.85	0.033
B	0.35	0.014
C	0.35	0.014
D	0.35	0.014
E	0.20	0.008



Standard Packaging

Case Type	REEL PACK	
	REEL (pcs)	Reel Size (inch)
DFN06P /DFN1010	5,000	7